

2A, 16V, Synchronous Step-down DCDC converter

## MM4008

### Overview

A step-down DC / DC converter for secondary car infotainment equipment. The high-precision oscillation frequency of  $1.9\text{MHz} \pm 5\%$  avoids noise interference in the AM band, and the output MOSFET with low on-resistance operates with high efficiency.

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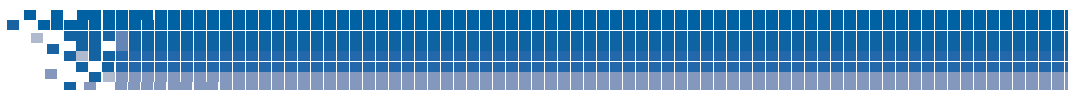
### FEATURES

- Input Voltage range 4.5V-16V
- Output current 2A
- High-side, Low-side Internal FET Switch  
High side :  $100\text{m}\Omega$  typ. / Low side :  $65\text{m}\Omega$  typ.
- Overcurrent detection Space saving with high accuracy
- Suppression of output overvoltage by output mild recovery function
- High efficiency operation 12V input, 88% or more at 2A
- Noise reduction by spread spectrum function
- Built-in P\_GOOD flag function

### Package

- SQFN-16C 3.0 × 3.0 × 0.75 [mm]





## TERMINAL EXPLANATIONS

SQFN-16C	PIN No.	Name	Function
	1,2	VIN	Power supply pin. Input power supply voltage 4.5-16V. Place ceramic capacitors as close to the pins as possible.
	4	CE	Chip enable pin. Pull above 2.0V to enable, pull below 0.6V to disable. Please avoid use in the that is floating.
	5	SS	Soft-start time adjustable pin. Soft-start time can be set up by adjusting an external capacitor.
	7	SP	Spread spectrum modulation frequency setting pin. The modulation frequency can be set by adjusting the external capacitance. When not using the spread spectrum function, connect to GND.
	8	P_GOOD	Reset output pin. Open drain reset output pin. L signal is outputted when the abnormal operation is detected. In not using a P_GOOD pin, please connect to GND.
	9	VO	Output voltage feedback pin. When the output voltage is set to 5V or higher, power is supplied from the output to the internal circuit.
	11	VDD	Internal linear regulator output pin. The internal circuitry is powered from this voltage. Place ceramic capacitors as close to the pins as possible.
	12	BS	Bootstrap capacitor connection pin. The bootstrap capacitor 0.1μF is necessary between BS to SW to drive the high side switch.
	13	GND	Ground pin.
	14,15	SW	Inductor connection pin.
	17	GND	Ground terminal, thermal pad. Connect it to the ground to obtain the optimum electrical characteristics.
	3,6,10,16	N.C.	No connection.

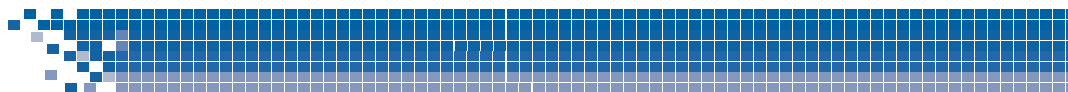
## ABSOLUTE MAXIMUM RATINGS

(Ta=25°C and AGND standard, unless otherwise specified.)

ITEM	SYMBOL	MIN.	MAX.	UNIT
VIN supply voltage	V <sub>INMAX</sub>	-0.3	18	V
SW pin voltage	V <sub>SWMAX</sub>	-0.3	V <sub>IN</sub> +0.3	V
BS pin voltage	V <sub>BSMAX</sub>	V <sub>SW</sub> -0.3	V <sub>SW</sub> +5.5	V
VO pin voltage	V <sub>VOMAX</sub>	-0.3	18	V
CE pin voltage	V <sub>CEMAX</sub>	-0.3	5.5	V
SS pin voltage	V <sub>SSMAX</sub>	-0.3	3	V
SP pin voltage	V <sub>SPMAX</sub>	-0.3	3	V
VDD pin voltage	V <sub>VDDMAX</sub>	-0.3	5.5	V
P_GOOD pin voltage	V <sub>PGOODMAX</sub>	-0.3	5.5	V
Storage temperature	T <sub>stg</sub>	-55	150	°C
Power dissipation *1	P <sub>d</sub>	-	3.7	W

\*1 Board conditions FR4, 6 layers, 80x80x1.6t mm, copper foil ratio 90%.





## RECOMMENDED OPERATING CONDITIONS

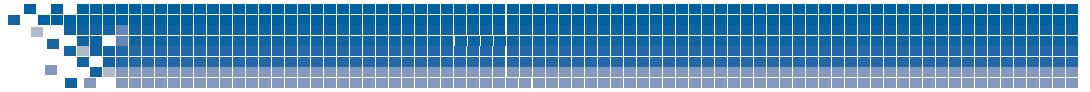
ITEM	SYMBOL	MIN.	MAX.	UNIT
Operating Ambient temperature	Topr	-40	105	°C
Operating voltage	Vop	4.5	16	V

## ELECTRICAL CHARACTERISTICS

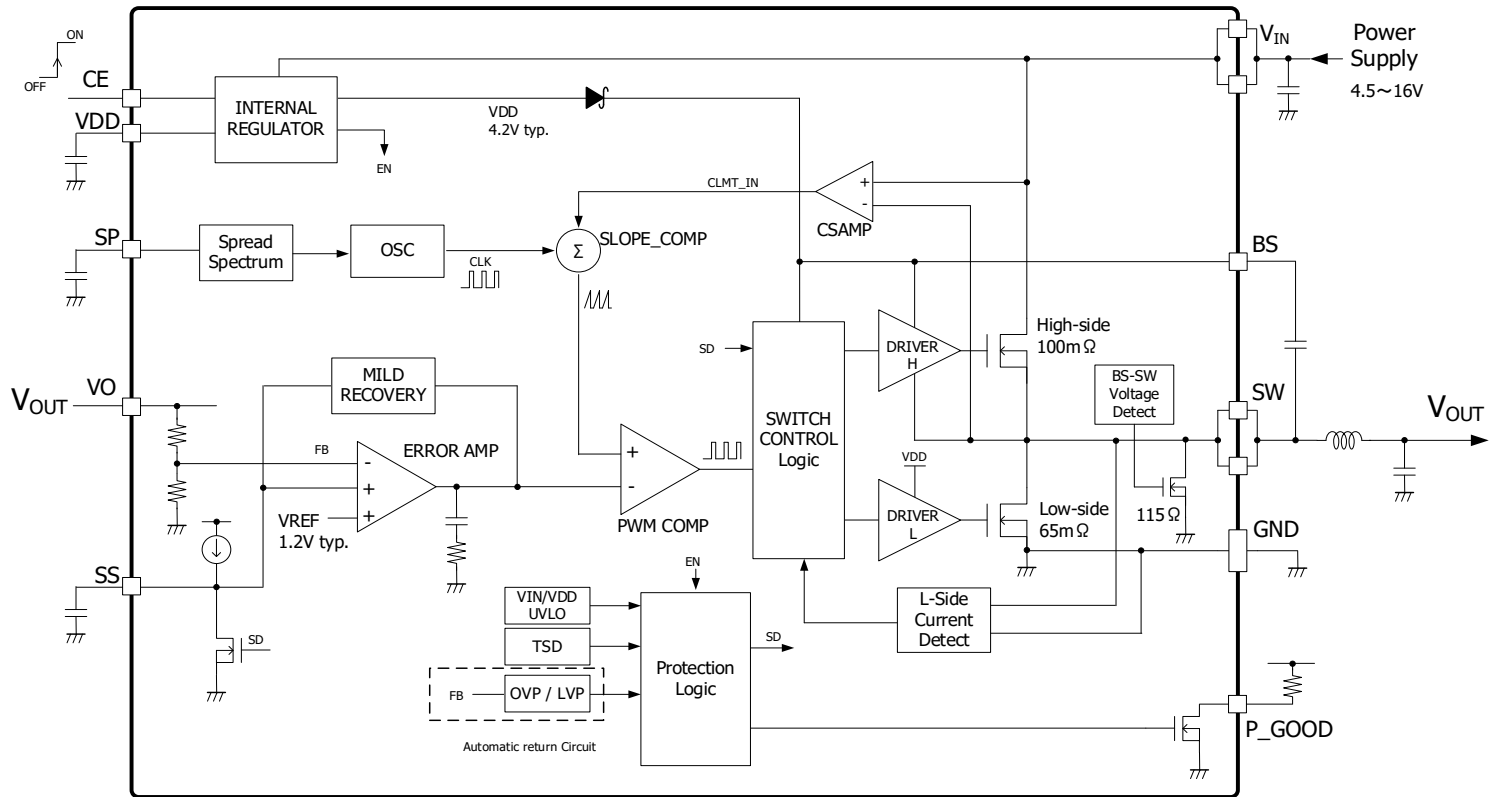
(unless otherwise specified VIN=10V,CE=3V,Ta=25°C)

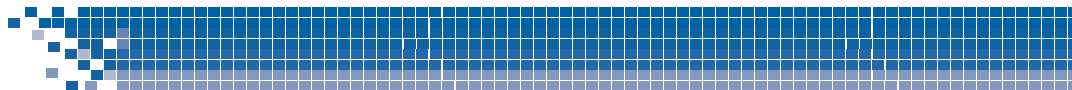
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	UNIT
Supply Current	IS1	No switching	-	1.5	2.1	mA
Shutdown Current	IS2	VCE=0V,VIN=16V	-	0.01	1.0	uA
VO pin Voltage	VOUT	No Load	3.267	3.300	3.333	V
VO pin Voltage Temperature coefficient *2	-	Tj=-40 to 105°C	-50	-	50	ppm/°C
VO pin Input Current	I <sub>VO</sub>	No switching	-	25	40	μA
High-side switch on-resistance *2	R <sub>ONH</sub>	V <sub>GS</sub> =4.2V	-	100	-	mΩ
Low-side switch on-resistance *2	R <sub>ONL</sub>	V <sub>GS</sub> =4.2V	-	65	-	mΩ
High-side switch leakage current	I <sub>LEAKH</sub>	V <sub>CE</sub> =V <sub>SW</sub> =0V,V <sub>IN</sub> =16V	-	0.01	1	μA
Low-side switch leakage current	I <sub>LEAKL</sub>	V <sub>CE</sub> =0V,V <sub>SW</sub> =V <sub>BS</sub> =16V	-	0.01	1	μA
Oscillation frequency	f <sub>SW</sub>	SP=0V,Tj=-40 to 150°C *2	1.81	1.90	2.00	MHz
Minimum On Time	T <sub>ONMIN</sub>		-	60	80	ns
Minimum Off Time	T <sub>OFFMIN</sub>		-	80	100	ns
VDD Output Voltage	V <sub>VDD</sub>		-	4.2	-	V
VIN UVLO detection voltage	V <sub>UVLO_VIN</sub>	V <sub>IN</sub> =high to low	3.8	4.0	4.2	V
VIN UVLO hysteresis voltage	ΔV <sub>UVLO_VIN</sub>	V <sub>IN</sub> =low to high	0.1	0.2	0.3	V
VDD UVLO detection voltage	V <sub>UVLO_VDD</sub>	V <sub>VDD</sub> =high to low	3.0	3.2	3.4	V
VDD UVLO hysteresis voltage	ΔV <sub>UVLO_VDD</sub>	V <sub>VDD</sub> =low to high	0.25	0.40	0.55	V
CE pin H threshold voltage	V <sub>CETH</sub>		2.0	-	-	V
CE pin L threshold voltage	V <sub>CETL</sub>		-	-	0.6	V
CE pin input current	I <sub>CE</sub>	V <sub>CE</sub> =3.3V	-	8	15	μA
OVP detection voltage	V <sub>OVP</sub>	V <sub>VO</sub> =low to high	110	115	120	%
OVP detection delay time *2	T <sub>DLY_OVP</sub>		-	-	10	μs
OVP detection latch delay time	T <sub>LATCH_OVP</sub>		0.7	1.0	1.3	ms
LVP detection voltage	V <sub>LVP</sub>	V <sub>VO</sub> =high to low	40	50	60	%
LVP detection latch delay time	T <sub>LATCH_LVP</sub>		0.7	1.0	1.3	ms
Latch OFF Automatic return time	T <sub>R_DLY</sub>		140	200	260	ms
High-side current limit *2	I <sub>LMTH</sub>		3.3	3.5	3.7	A
Low-side current limit *2	I <sub>LMTL</sub>		1.5	3.0	4.0	A
Thermal shutdown *4	TSD		-	170	-	°C
Thermal shutdown hysteresis *4	ΔTSD		-	30	-	°C
SS pin current	I <sub>SS</sub>	V <sub>SS</sub> =0.4V, V <sub>VO</sub> =V <sub>OUT</sub> *1.05	1.2	2.5	3.8	ms
Spread spectrum modulation frequency	f <sub>SS</sub>	C <sub>SP</sub> =2200pF	-	3	-	kHz
Spread Spectrum Modulation Frequency Range	-		-	20	-	%
SP pin current	I <sub>SP</sub>	V <sub>SP</sub> =1.1V	-	±4.0	-	μA
SW pin discharge resistance	R <sub>SW_DIS</sub>		-	115	150	Ω
P_GOOD pin leakage current	I <sub>LEAK_PG</sub>	V <sub>PGOOD</sub> =5.5V	-	-	1	μA
P_GOOD pin sink current	I <sub>SINK_PG</sub>	V <sub>PGOOD</sub> =0.5V	1	2	-	mA

\*2 Guaranteed by design, not tested.

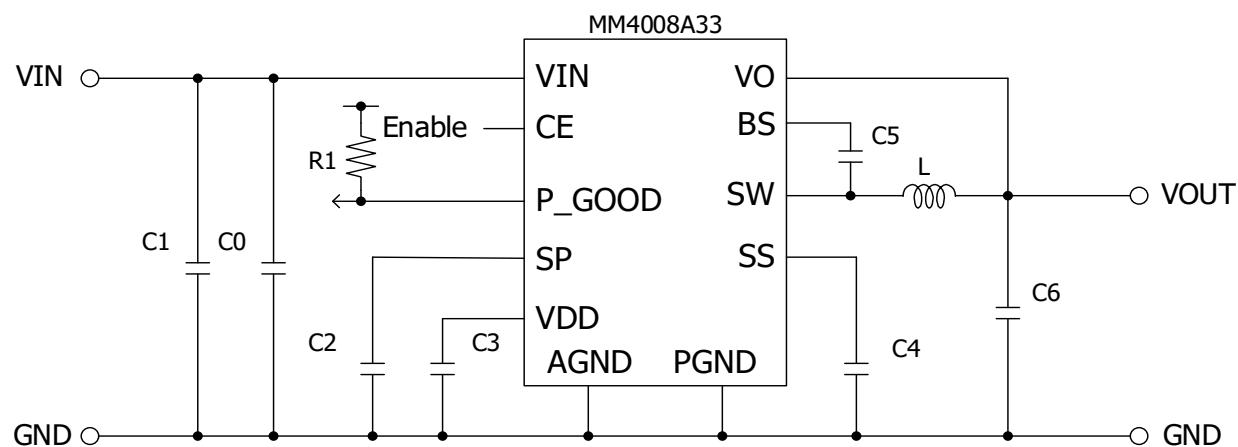


## BLOCK DIAGRAM





## TYPICAL APPLICATION CIRCUIT



C0 - C8 Ceramic capacitor

Table1. Recommended external parts value.

L [μH]	R1 [kΩ]	C0 [μF]	C1 [μF]	C2 [pF]	C3 [μF]	C4 [μF]	C5 [μF]	C6 [μF]
2.2	10	0.1	10	2200	2.2	0.01	0.1	22

Soft start time calculation formula

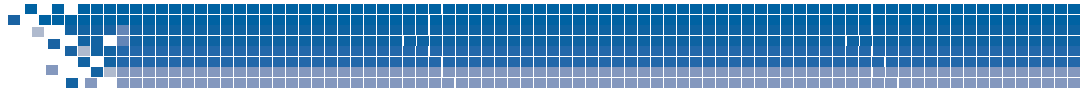
$$T_{SS} = \frac{1.14 \times C4}{I_{SS}} + T_{DELAY} \quad [\text{sec}]$$

\* T<sub>DELAY</sub> : VDD start up delay time 100μs(typ)

### Application hints

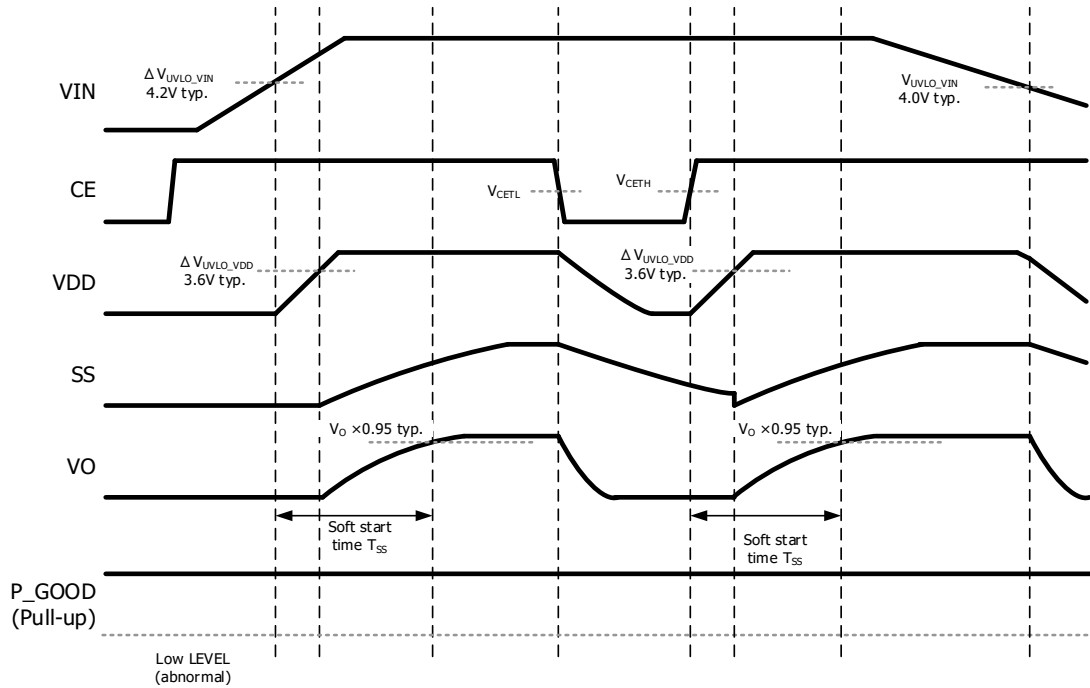
The output voltage is decided depending on the input voltage, Minimum on time, Maximum duty cycle. Please decide the output condition in consideration of the above-mentioned characteristic. There is a possibility that operation becomes unstable when the current rating of the coil is exceeded. Please enlarge the current rating of the coil more than the output current.





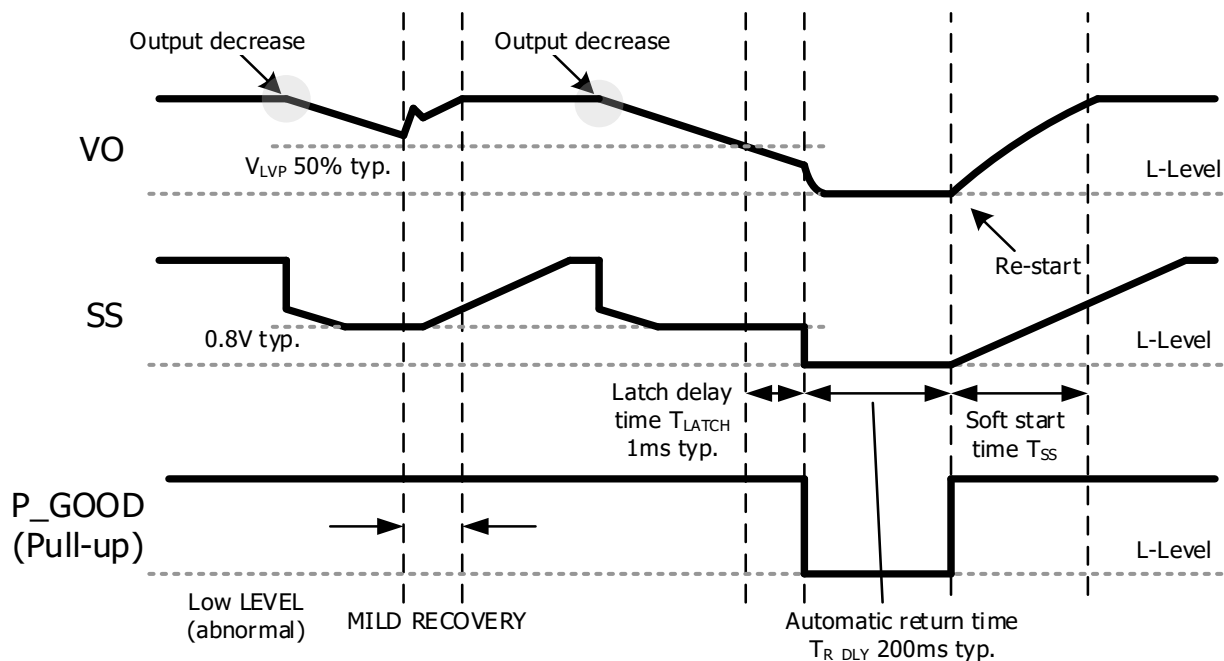
## TIMMING CHART

### Start-up/ Shut-down

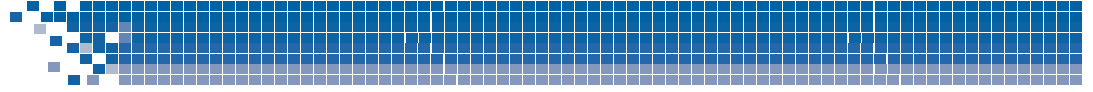


Start-up condition is  $V_{CE} > V_{CET}$  and  $V_{IN} > V_{UVLO\_VIN}$ . Shut-down condition is  $V_{CE} < V_{CET}$  or  $V_{IN} < V_{UVLO\_VIN}$ . Soft start time  $T_{SS}$  is from  $V_{CE} > V_{CET}$  to time that  $V_{OUT}$  is up to reach 95% of the normal value.

### Low output voltage protection

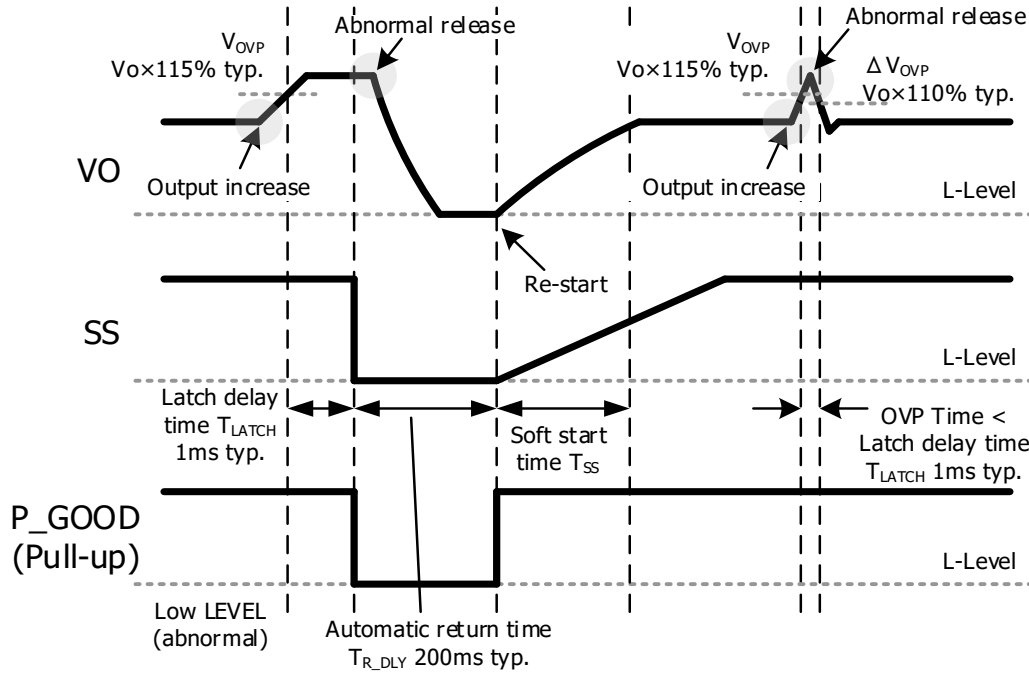


When LVP are detected exceeding latch delay time  $T_{LATCH}$ , the IC is shutdown, P\_GOOD is L-Output. After 200ms, the IC will automatically return in soft-start operation.



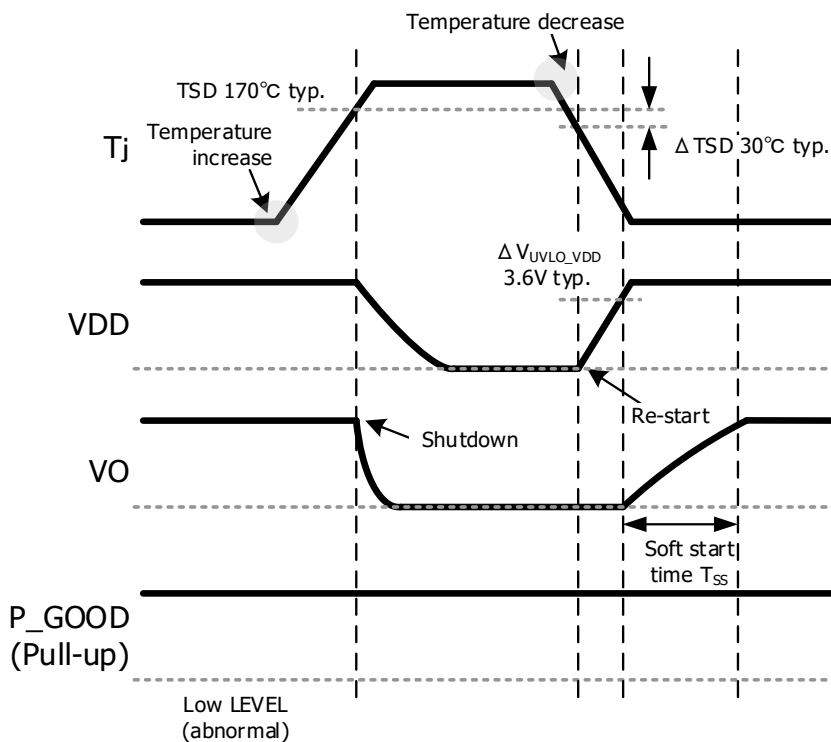
## TIMMING CHART (CONTINUED)

### Over output voltage protection



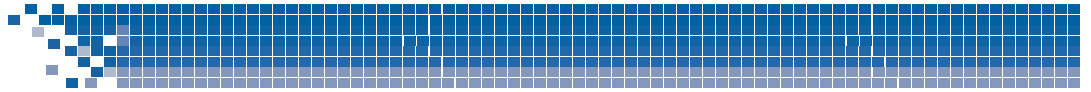
When OVP is detected, the IC stops switching. If OVP is detected exceeding latch delay time  $T_{LATCH}$ , the IC is shutdown, P\_GOOD is L-Output. After 200ms, the IC will automatically return in soft-start operation.

### Thermal shutdown function



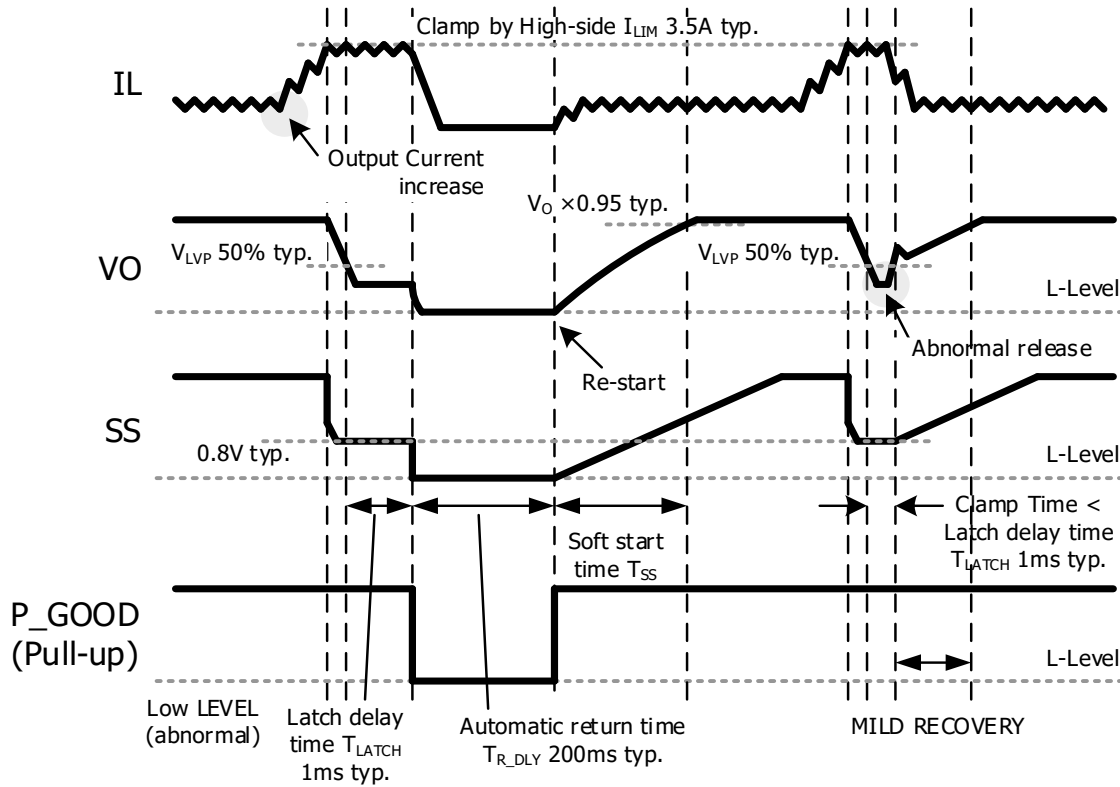
When the junction temperature ( $T_j$ ) rises above 170 °C, VDD stops, and the IC shuts it down. When the junction temperature ( $T_j$ ) drops below 140 °C, the IC will restart.





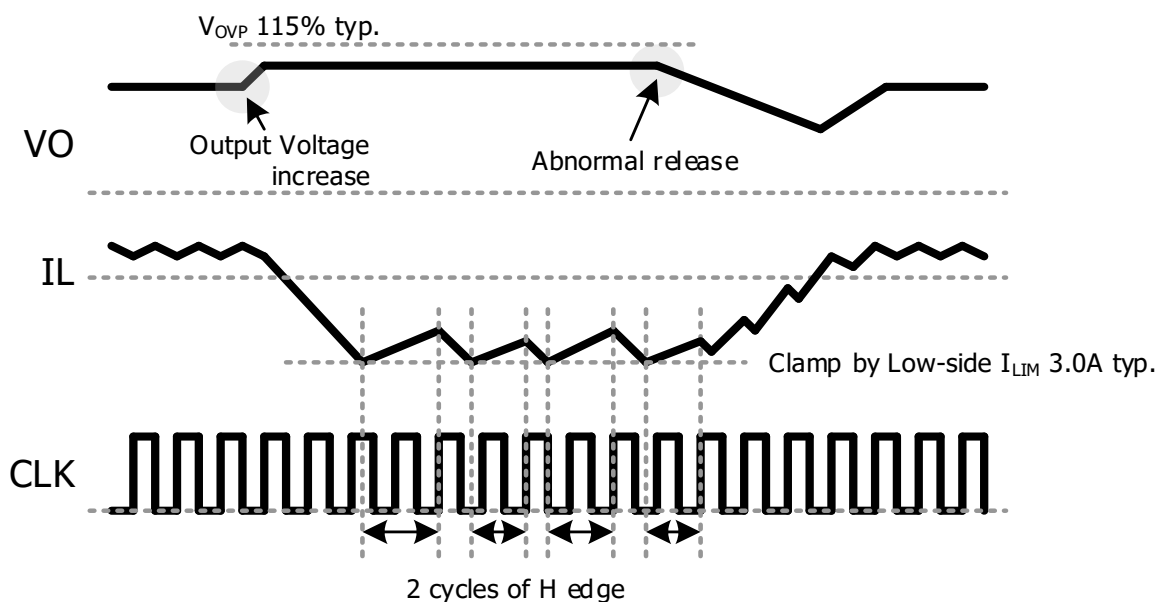
## TIMMING CHART (CONTINUED)

### High-side current limit function



The IC limits the current flowing through the high side  $T_r$  to 3.5A (typ.) or less. If the output voltage drops due to current limitation, the mild recovery function will operate.

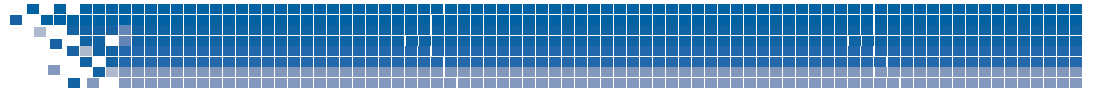
### Low-side current limit function



The IC limits the current flowing through the low-side  $T_r$  to 3.0A (typ.) or less. When the low-side current limit is detected, the IC keeps turning off the high-side and low-side  $T_r$  for two cycles of the oscillation frequency. When the current falls below the specified value, it returns to normal switching operation.

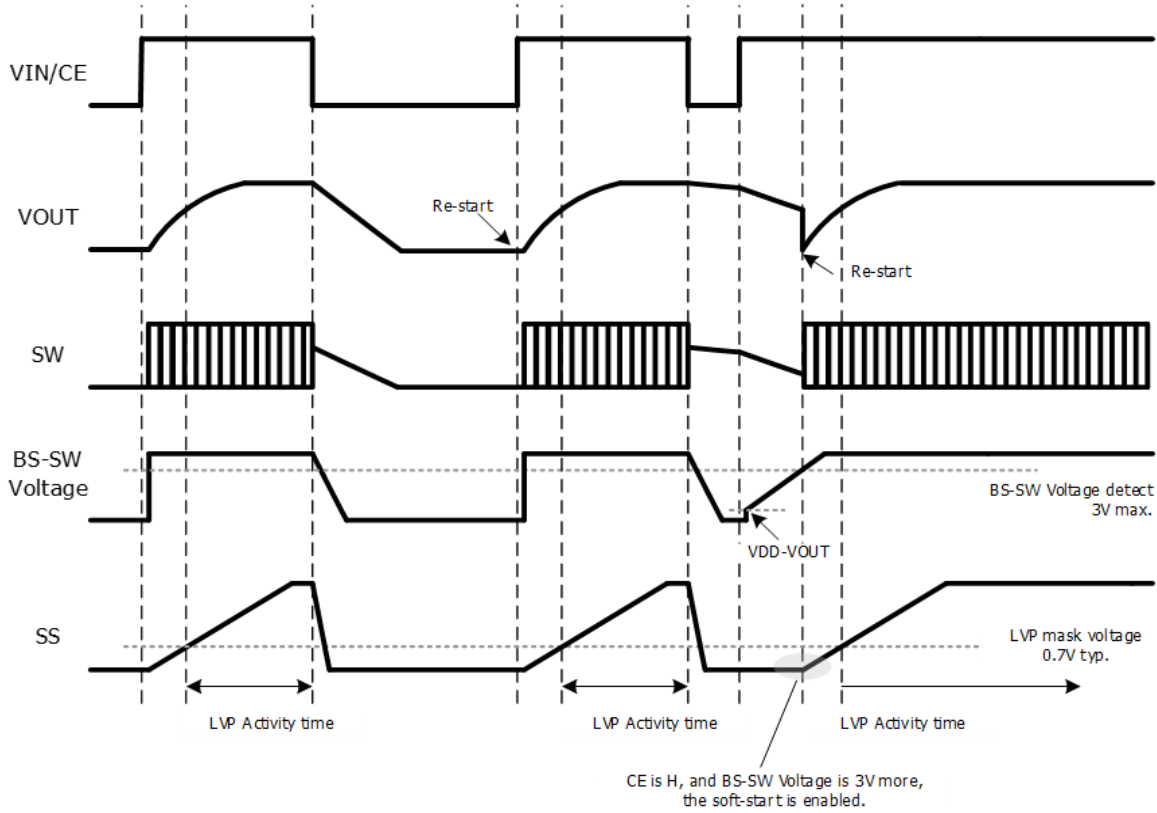






## TIMMING CHART (CONTINUED)

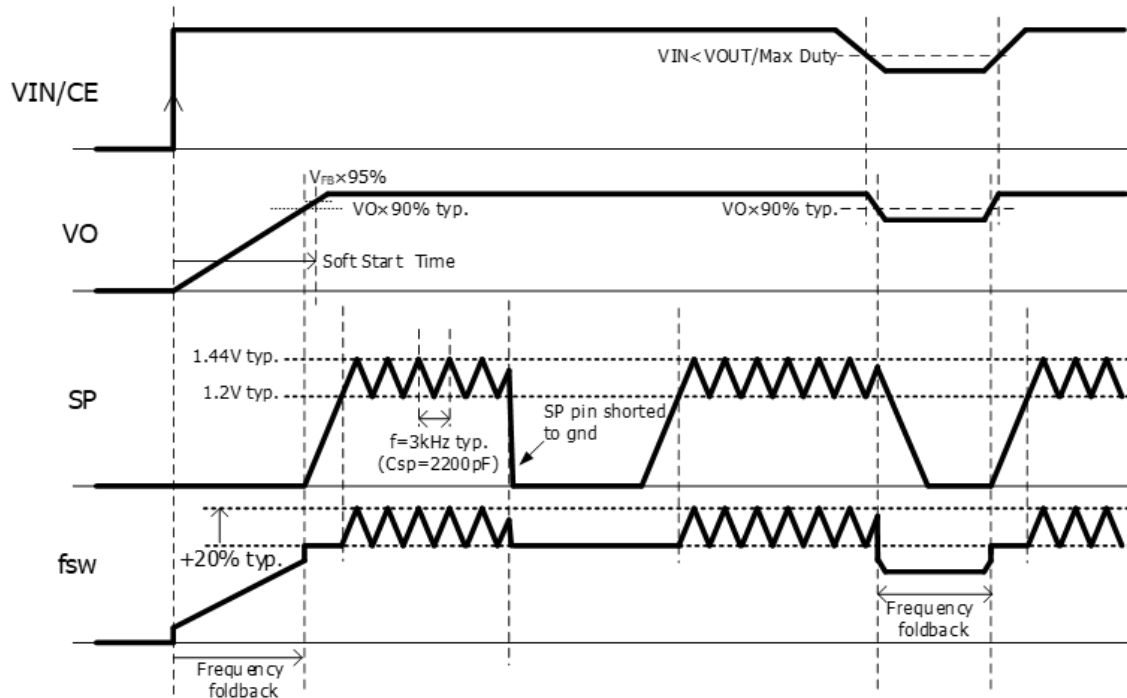
### Restart-up



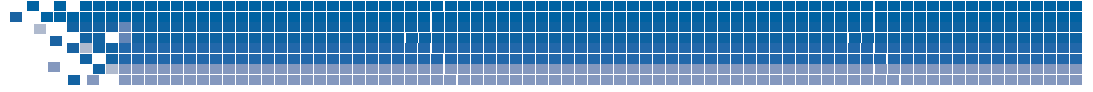
In the case of Restart, please note for a change in the behavior of the start-up by the charge of  $V_{OUT}$ .

When the charge of the output remains, if BS-SW voltage is not reached to the detection voltage (3V max.) or more, the IC does not start the soft-start.

### Spread spectrum function



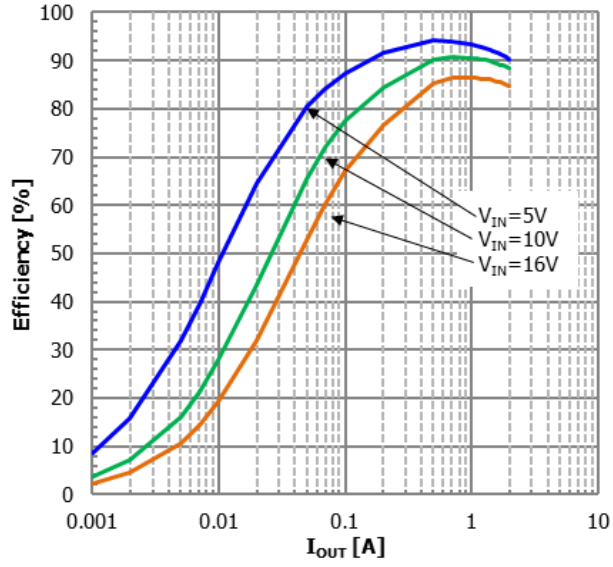
The start condition of the spread spectrum function is  $V_O > V_O \times 90\%$ . When  $V_{SP} \geq 1.2V$ , the IC changes the oscillation frequency with +20% triangular wave frequency modulation.



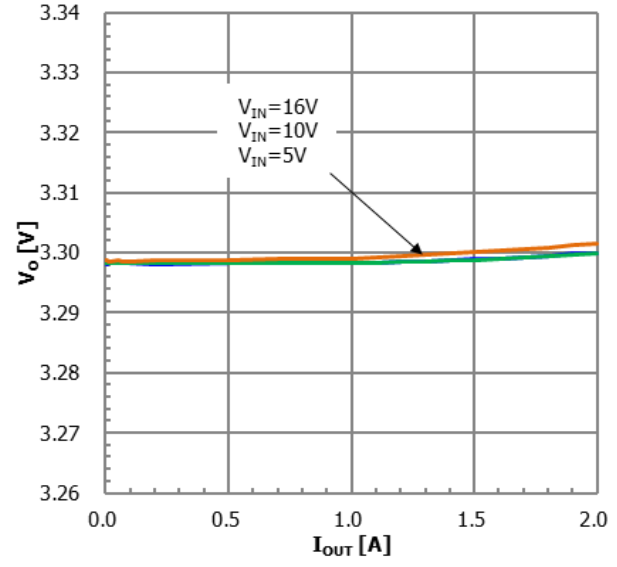
## TYPICAL PERFORMANCE CHARACTERISTICS

(Unless otherwise specified,  $V_{IN}=10V$ ,  $V_{CE}=3V$ ,  $C_{SP}=2200pF$ ,  $T_a=25^\circ C$ )

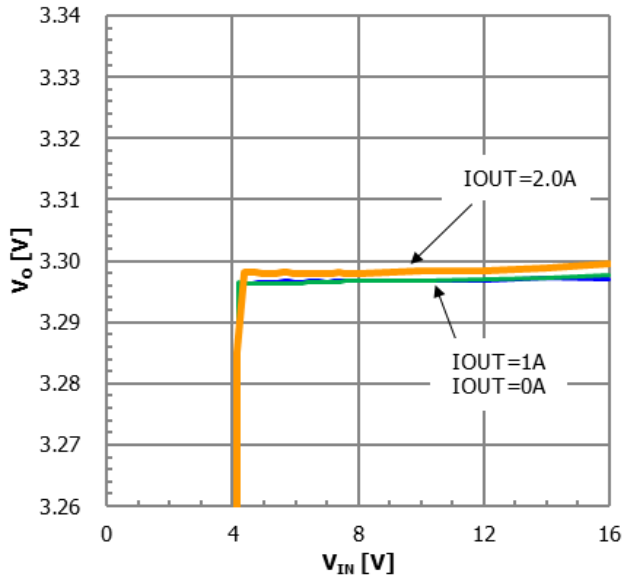
Efficiency



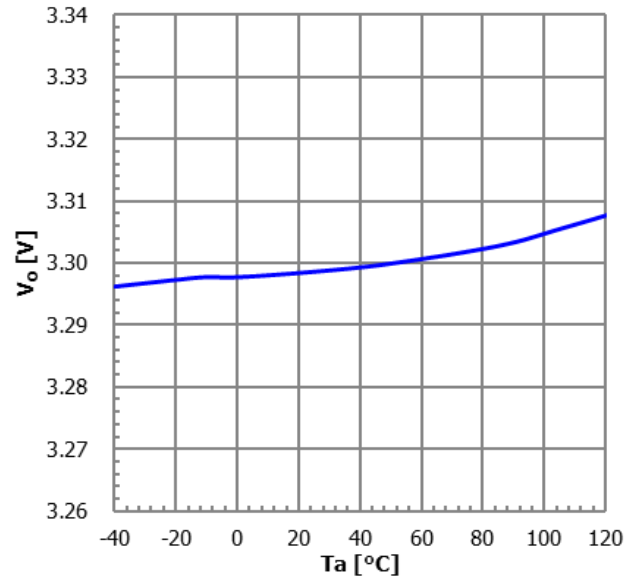
Load regulation



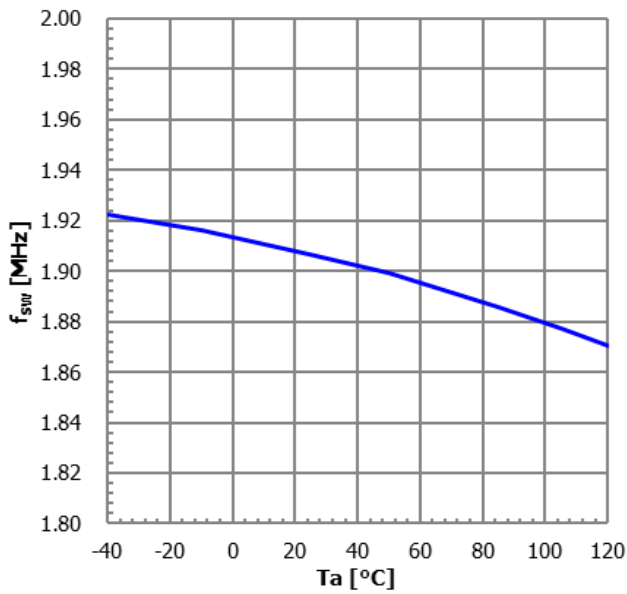
Line regulation



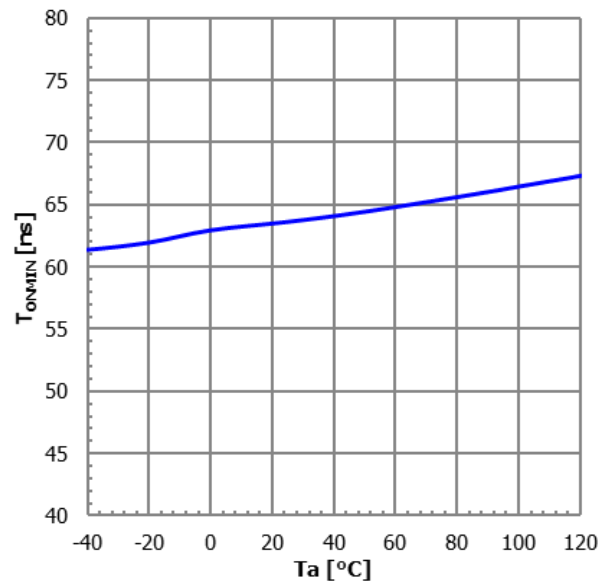
VO pin voltage vs Temperature

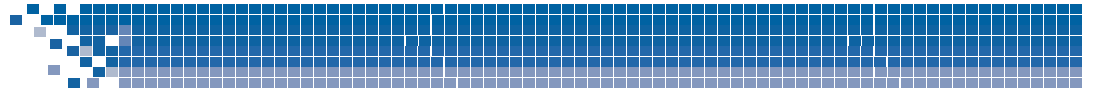


Oscillation frequency vs Temperature (SP=0V)



Minimum on time vs Temperature

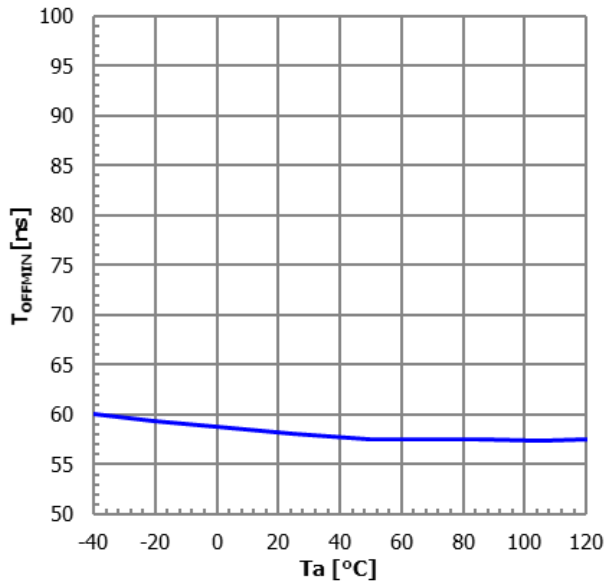




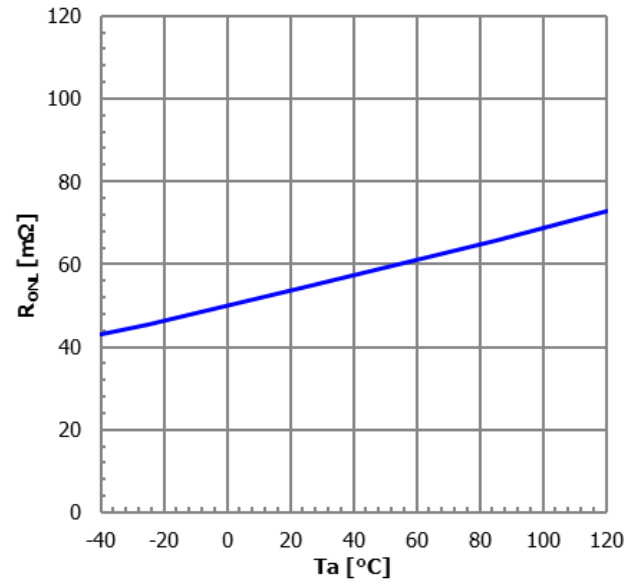
## TYPICAL PERFORMANCE CHARACTERISTICS (CONTINUED)

(Unless otherwise specified,  $V_{IN}=10V$ ,  $V_{CE}=3V$ ,  $C_{SP}=2200pF$ ,  $T_a=25^\circ C$ )

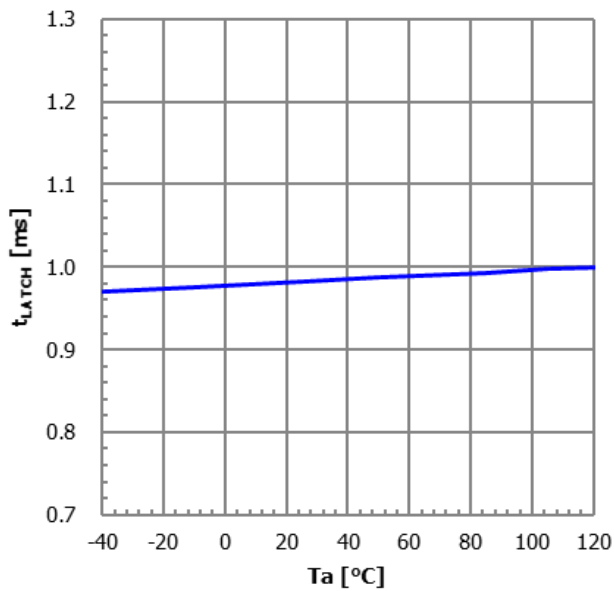
Minimum off time vs Temperature



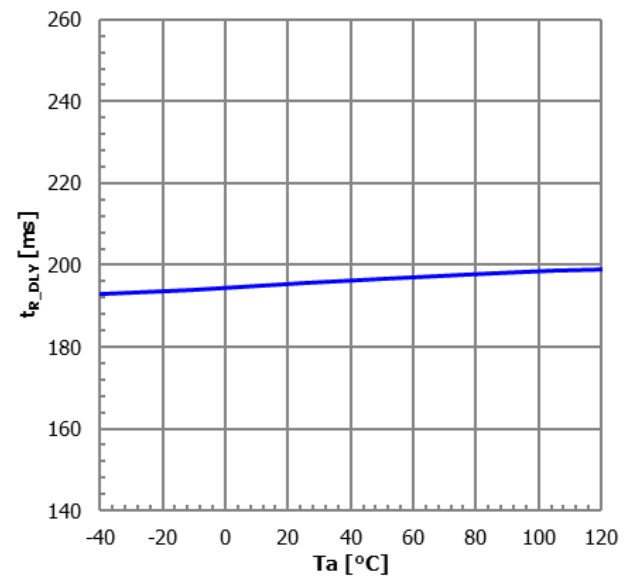
Low-side switch on-resistance vs Temperature



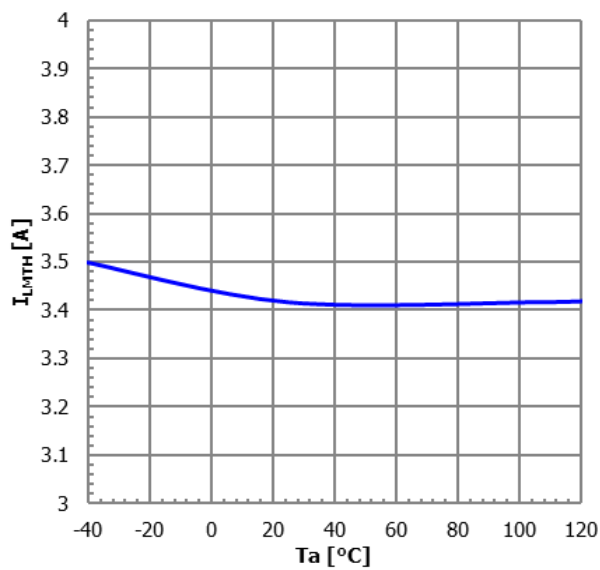
Latch delay time vs Temperature



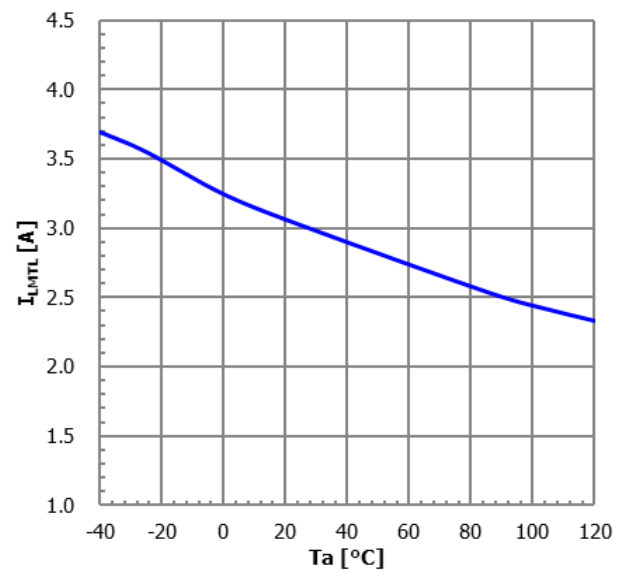
Latch OFF Automatic return time vs Temperature

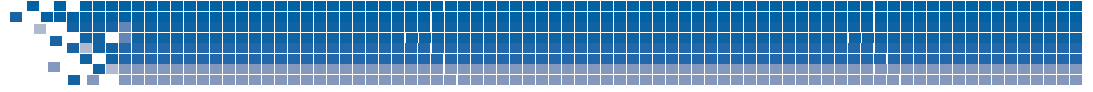


High-side current limit vs Temperature



Low-side current limit vs Temperature

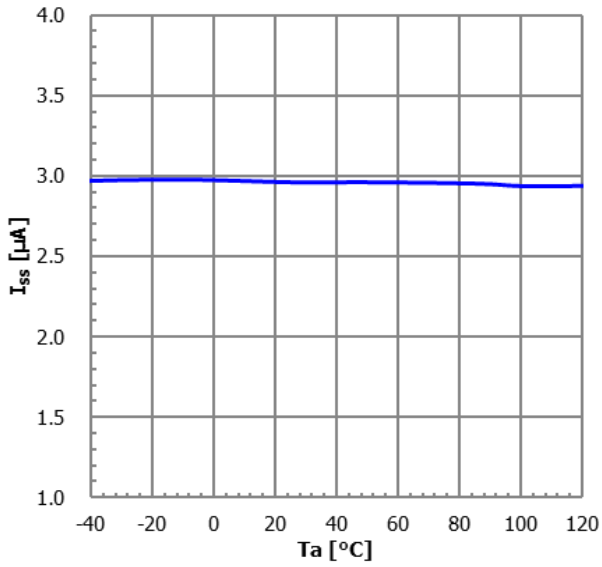




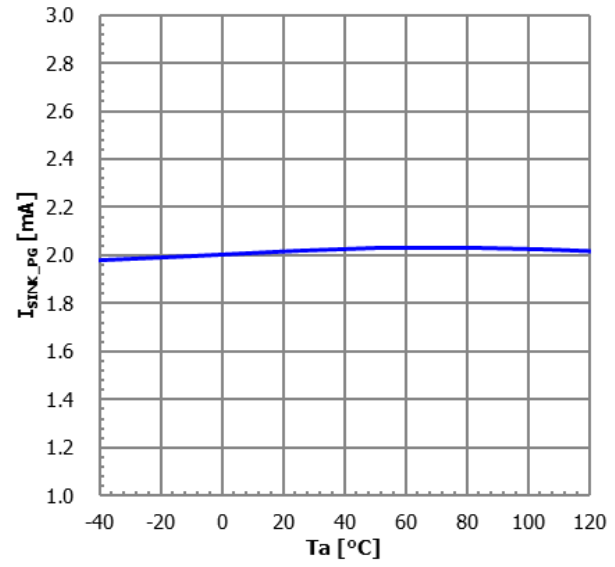
## TYPICAL PERFORMANCE CHARACTERISTICS (CONTINUED)

(Unless otherwise specified,  $V_{IN}=10V$ ,  $V_{CE}=3V$ ,  $C_{SP}=2200pF$ ,  $T_a=25^\circ C$ )

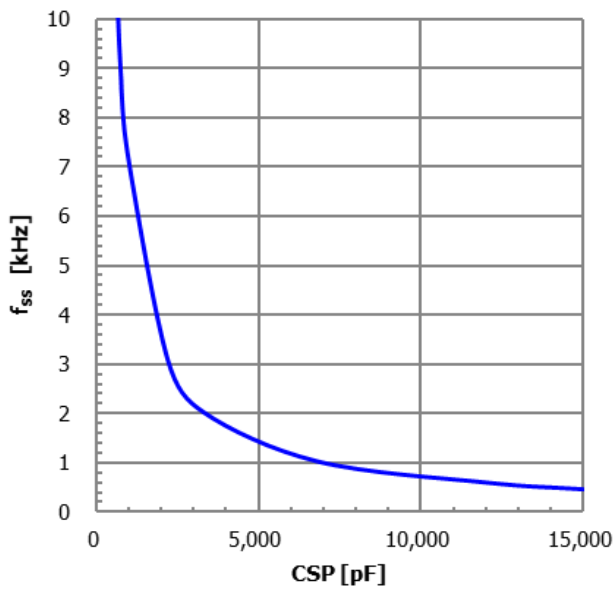
SS pin current vs Temperature



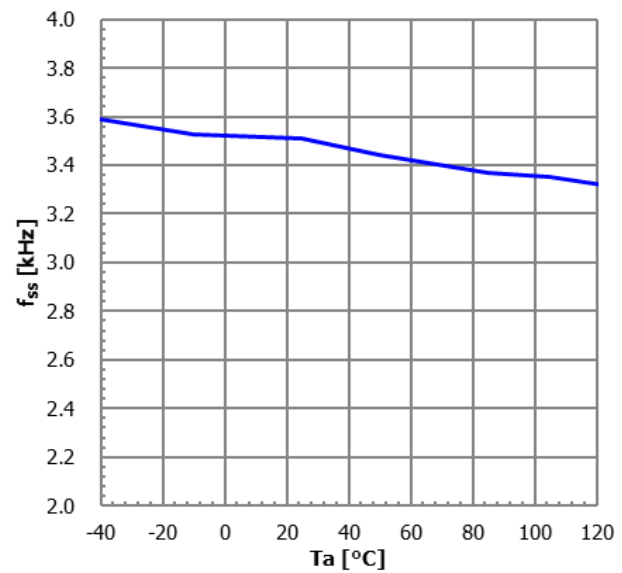
P\_GOOD pin sink current vs Temperature



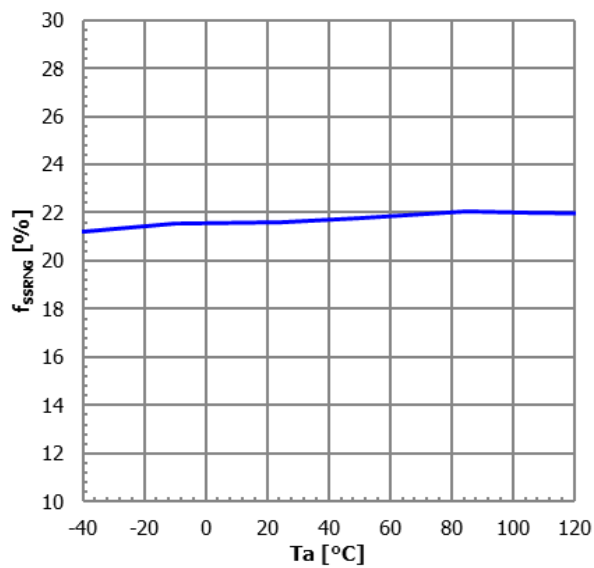
Modulation Frequency vs  $C_{SP}$



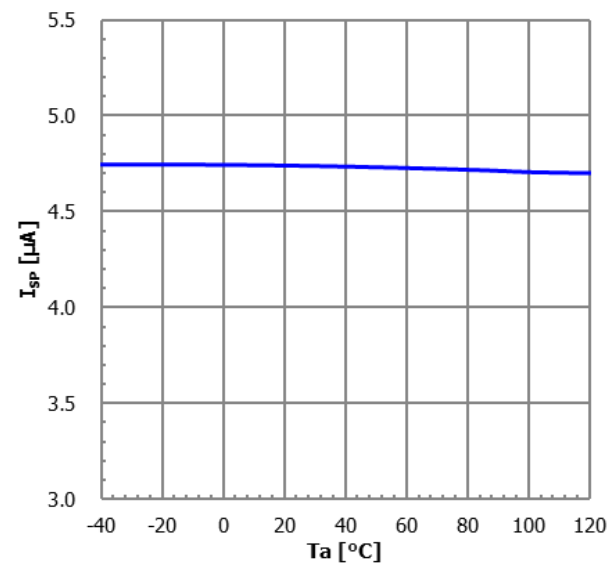
Modulation Frequency vs Temperature

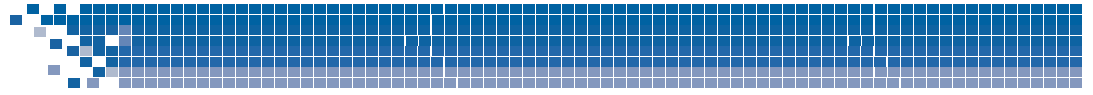


Modulation Frequency Range vs Temperature



SP pin current vs Temperature

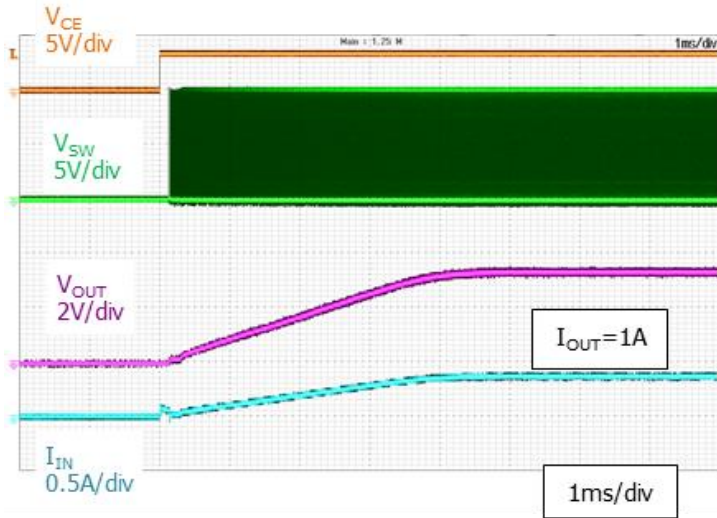




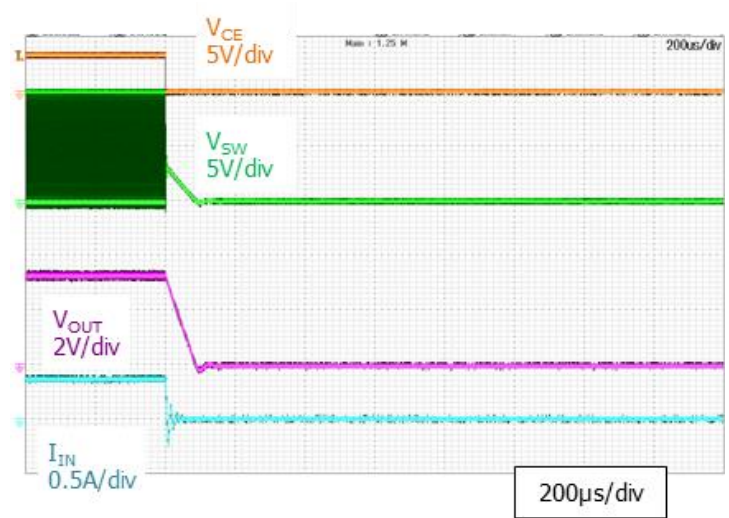
## TYPICAL PERFORMANCE CHARACTERISTICS (CONTINUED)

(Unless otherwise specified,  $V_{IN}=10V$ ,  $V_{CE}=3V$ ,  $C_{SP}=2200pF$ ,  $T_a=25^\circ C$ )

Start-up



Shutdown



Load transient response

